

SANYO Semiconductors DATA SHEET

2SC5538A — VHF to UHF Band OSC, High-Frequency Amplifier Applications

Features

• High gain : $|S21e|^2=10.5dB$ typ (f=1GHz).

• High cut-off frequency: fT=5.2GHz typ.

• Ultrasmall, slim flat-lead package (1.4mm×0.8mm×0.6mm).

· Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		10	V
Emitter-to-Base Voltage	VEBO		2	V
Collector Current	IC		100	mA
Collector Dissipation	PC		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Faranielei	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	ICBO	V _{CB} =10V, I _E =0A			1.0	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0A			10	μΑ
DC Current Gain	hFE1	VCE=3V, IC=7mA	110		200	
DC Current Gain	hFE2	V _{CE} =3V, I _C =30mA	100			
Gain-Bandwidth Product	fT	V _{CE} =3V, I _C =7mA	3	5.2		GHz
Output Capacitance	Cob	V _{CB} =3V, f=1MHz		1.0	1.5	pF
Reverse Transfer Capacitance	Cre	V _{CB} =3V, f=1MHz		0.7		pF

Marking: NA Continued on next page.

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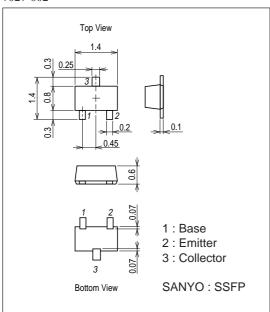
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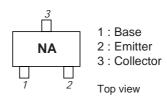
Parameter	Symbol	Symbol Conditions		Ratings		
	Gymbol	Conditions	min	typ	max	Unit
Forward Transfer Gain	S21e ²	VCE=3V, IC=7mA, f=1GHz	8	10.5		dB
Noise Figure	NF	V _{CE} =3V, I _C =7mA, f=1GHz		1.4	2.5	dB

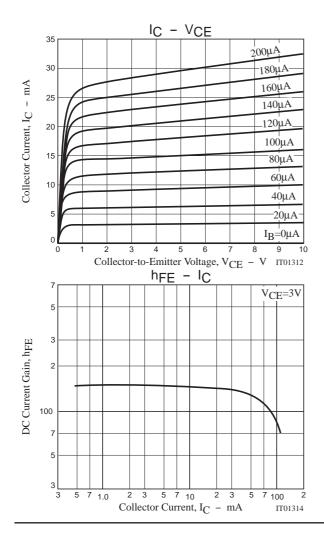
Package Dimensions

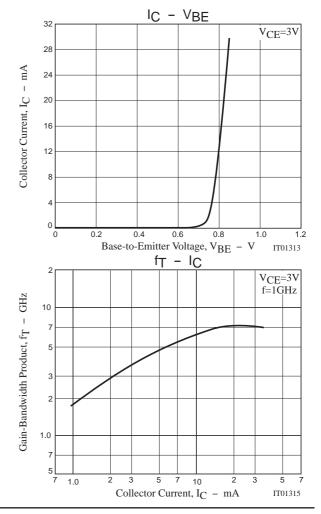
unit : mm (typ) 7027-002

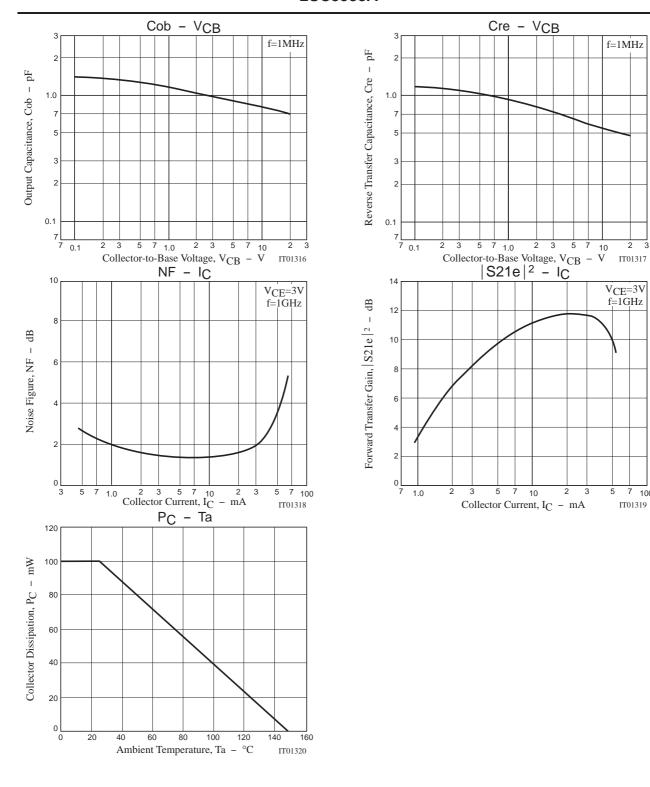


Marking









f=1MHz

V_{CE}=3V f=1GHz

7 100 IT01319

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S Parameters (Common emitter)

 $V_{CE}=1V$, $I_{C}=3mA$, $Z_{O}=50\Omega$

Freq(MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.874	-40.6	8.627	152.3	0.062	67.9	0.918	-23.4
200	0.785	-71.6	6.874	132.5	0.101	52.1	0.748	-41.7
400	0.651	-114.8	4.701	107.3	0.135	37.1	0.537	-57.6
600	0.613	-136.9	3.365	92.8	0.152	31.1	0.430	-65.6
800	0.581	-153.9	2.716	81.9	0.155	29.9	0.361	-74.3
1000	0.568	-164.2	2.218	73.4	0.161	30.0	0.326	-80.2
1200	0.556	-172.0	1.863	66.2	0.170	30.5	0.300	-86.1
1400	0.563	-178.1	1.626	59.6	0.177	32.7	0.297	-92.3
1600	0.558	175.4	1.473	53.9	0.185	35.4	0.306	-96.5
1800	0.560	168.9	1.345	48.1	0.196	37.4	0.313	-100.6
2000	0.567	163.1	1.230	42.5	0.205	38.0	0.335	-102.9

 $V_{CE}=3V$, $I_{C}=7mA$, $Z_{O}=50\Omega$

*CE 5 1, 2C 711								
Freq(MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.789	-48.3	16.232	147.7	0.039	66.1	0.862	-27.2
200	0.670	-83.7	12.431	126.4	0.061	53.0	0.673	-44.6
400	0.552	-123.8	7.607	104.7	0.081	45.2	0.438	-59.1
600	0.522	-145.3	5.401	92.7	0.094	45.9	0.333	-65.1
800	0.504	-158.5	4.155	84.1	0.106	48.2	0.290	-68.7
1000	0.488	-169.1	3.425	77.1	0.121	49.1	0.270	-71.0
1200	0.478	-176.1	2.849	71.0	0.136	51.0	0.253	-74.7
1400	0.481	178.4	2.511	65.6	0.152	52.2	0.239	-79.6
1600	0.478	172.7	2.237	60.7	0.167	52.8	0.240	-82.8
1800	0.492	167.4	2.016	55.5	0.185	53.2	0.245	-86.7
2000	0.489	162.0	1.844	50.5	0.200	52.7	0.248	-90.0

 $V_{\mbox{\footnotesize{CE}}=5}\mbox{\footnotesize{V}},\mbox{\footnotesize{Ic}}=20\mbox{\footnotesize{mA}},\mbox{\footnotesize{Z}}\mbox{\footnotesize{O}}=50\mbox{\footnotesize{\Omega}}$

Freq(MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.643	-66.4	26.381	137.4	0.029	62.8	0.748	-36.3
200	0.530	-104.6	17.543	116.5	0.041	54.2	0.531	-52.5
400	0.459	-140.3	9.835	98.9	0.058	55.4	0.322	-62.7
600	0.447	-157.2	6.805	89.4	0.074	59.2	0.246	-65.5
800	0.440	-168.4	5.210	82.4	0.092	61.4	0.213	-68.6
1000	0.434	-175.9	4.194	76.6	0.110	61.9	0.199	-70.2
1200	0.437	177.1	3.518	71.5	0.129	62.3	0.191	-72.9
1400	0.437	173.0	3.077	66.7	0.148	61.8	0.184	-76.5
1600	0.438	168.4	2.730	62.5	0.166	61.6	0.181	-80.9
1800	0.439	164.2	2.459	58.0	0.186	60.7	0.186	-84.8
2000	0.444	159.1	2.249	53.5	0.203	59.5	0.192	-87.3

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